

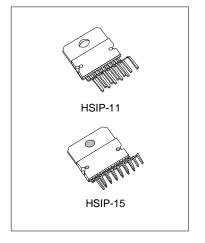
# 2-CH AUDIO POWER AMPLIFIER (20W X 2)

#### **DESCRIPTION**

The SA7267 is a monolithic integrated circuit in HSIP package, intended for use as dual audio frequency class AB amplifier.

### **FEATURES**

- \* Wide supply voltage range(up to  $\pm\,20\text{V}$  )
- \* Split supply operation.
- \* High output power: 20W+20W @ THD=10%, RL=4 $\Omega$ , Vs=±15V
- \* Mute/stand-by function.
- \* Few external components.
- \* Short circuit protection.
- \* Thermal shutdown protection.



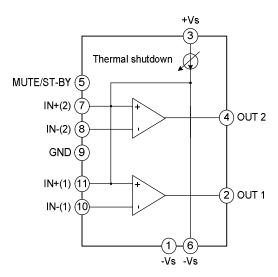
### **APPLICATIONS**

- \* Hi-Fi music centers
- \* Stereo TV sets

# ORDERING INFORMATION

Part No.	Package
SA7267	HSIP-11
SA7267A	HSIP-15

## **BLOCK DIAGRAM**



Note: Figures for the SA7267.



## ABSOLUTE MAXIMUM RATING

Characteristics	Symbol	Rating	Unit
DC Supply Voltage	Vs	40	V
Output Peak Current (Internally Limited)	lo	3	Α
Power Dissipation Tcase=70°C	Ptot	40	W
Storage And Junction Temperature	Tstg, Tj	-40~+150	°C
Supply voltage to guarantee short-circuit protection	Vs(sc)	±18(*)	V
Thermal Resistance From Junction To Case (Max)	Rth(j-c)	2	°C/W

<sup>(\*)</sup>Maximum supply voltage to guarantee short-circuit to ±Vs is ±18V, and to GND short-circuit protection is normal.

## **ELECTRICAL CHARACTERISTICS**

(Refer to the test circuit, Vs=±15V; RL=4Ω; Rs=50Ω; Gv=30dB; f=1KHz; Tamb=25°C, unless otherwise specified.)

(Neier to the test circuit, VS=±13V, I	(L=+32, 103	-5052, GV-500B, I=11(12, 12)	1110-20 0,	dilicos oti	ici wise sp	occinca.)
Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Supply Range	Vs		±5		±20	V
Total Quiescent Current	lq			50	100	mA
Input Offset Voltage	Vos		-25		+25	mV
In-phase Input Bias Current	lb			500		nA
		THD=10%;				
Output Power	Ро	RL= $4\Omega$ ;		20		W
		RL=8Ω		12.5		W
		RL=8Ω; Po=1W; f=1KHz		0.03		%
		RL=8Ω;			0.7	%
		Po=0.1~5W;				
Total Harmonic Distortion	THD	f=100Hz~15KHz				
Total Harmonic Distortion	IND	RL=4Ω; Po=1W; f=1KHz		0.02		%
		RL= $4\Omega$ ;			1	%
		Po=0.1~5W;				
		f=100Hz~15KHz				
Constant	СТ	f=1KHz		70		dB
Cross Talk		f=10KHz	50	60		dB
Slew Rate	SR		6.5	8		V/μs
Open Loop Voltage Gain	GV			80		dB
	eN	A curve		3		μV
Total Noise Input Voltage		f=20Hz~22KHz		4	8	μV
Input Resistance	Ri		15	20		ΚΩ
Supply Voltage Rejection (each channel)	SVR	Fr=100Hz; Vripple=0.5Vrms		60		dB

(To be continued)

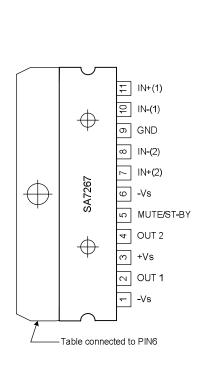
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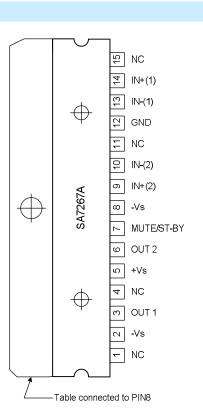


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Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Thermal Shut-down Junction	Tj			145		°C
Temperature	' ' '			145		C
Mute Function [ref: +Vs]						
Mute /Play Threshold	VTMUTE		-7	-6	-5	V
Mute Attenuation	AM		60	70		dB
Stand-by Function [ref: +Vs]						
Stand-by /Mute Threshold	VTst-by		-3.5	-2.5	-1.5	V
Stand-by Attenuation	AST-BY			110		dB
Quiescent Current @ Stand-by	lq ST-BY			3	6	mA

# PIN CONFIGURATION





# PIN DESCRIPTION

Pin No.		D. N.	1//0	5. 5	
HSIP-11	HSIP-15	Pin Name	I/O	Pin Description	
1	2	-Vs		Negative power	
2	3	OUT 1	0	Output1	
3	5	+Vs		Positive power	
4	6	OUT 2	0	Output2	
5	7	MUTE / ST-BY	I	Mute /stand-by function	

(To be continued)



#### (Continued)

Pin No.		D: N	1//0		
HSIP-11	HSIP-15	Pin Name	I/O	Pin Description	
6	8	-Vs		Negative power	
7	9	IN+(2)	1	Inverting Input 2	
8	10	IN-(2)	1	Non inverting input 2	
9	12	GND		Ground	
10	13	IN-(1)	1	Non inverting input 1	
11	14	IN+(1)	I	Inverting input 1	
	1,4,11,15	NC		Not connected	

#### **FUNCTION DESCRIPTION**

#### MUTE STAND-BY FUNCTION

The MUTE/ST-BY controls the amplifier status by two different thresholds, referred to +Vs.

- Ø When MUTE/ST-BY higher than +Vs 2.5V, the amplifier is in Stand-by mode and the final stage generators are off.
- Ø When MUTE/ST-BY is between +Vs 2.5V and +Vs- 6V, the final stage current generators are switched on and the amplifier is in mute mode
- Ø When MUTE/ST-BY is lower than +Vs 6V, the amplifier is in play mode.

### Power Dissipation and Heat Sinking

The SA7267 must always be operated with a heat sink. In order to determine the appropriate heat sink for a given application, the power dissipation of the SA7267 in that application must be known. When the load is a resistor, the maximum average power of the IC is approximately:

$$PD(MAX)=Vs^2/\pi^2RL+PQ$$

Where VS is the total power supply voltage across the SA7267, RL is the load resistance and PQ is the quiescent power dissipation of the amplifier. The above equation is only an approximation which assumes an "ideal" class B output stage and constant power dissipation in all other parts of the circuit. The curves of "Power Dissipation vs. Power Output" give a better representation of the behavior of the SA7267 with various power supply voltages and resistors. As an example, if the SA7267 is operated on a  $\pm 15$ V power supply with a resistance of  $4\Omega$ , it can develop up to 24.5W of internal power dissipation. If the die temperature is to remain below 150°C for ambient temperatures up to 50°C, the total junction-to-ambient thermal resistance must be less than:

Using Rth(j-c) =  $2^{\circ}$ C /W, the sum of the case-to-heat-sink interface thermal resistance and the heat-sink-to-ambient thermal resistance must be less than 2.1°C/W. The case-to-heat-sink thermal resistance of the HSIP-11 package varies with the mounting method used. A metal-to-metal interface will be about 1°C /W if use the thermal resistance, and about 1.2°C /W if not.

If a mica insulator is used, the thermal resistance will be about 1.6°C /W lubricated and 3.4°C /W dry. For this example, we assume a lubricated mica insulator between the SA7267 and the heat sink. The heat sink thermal resistance must then be less than:

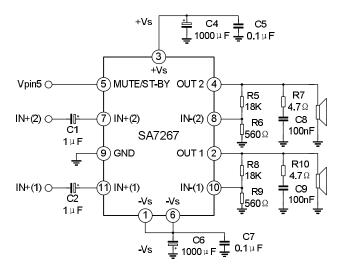
4.1°C/W-2°C/W-1.6°C/W=0.5°C/W

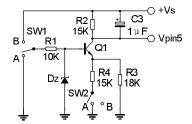


This is a rather large heat sink and may not be practical in some applications. If a smaller heat sink is required for reasons of size or cost, the heat sink can be isolated from the chassis so the mica washer is not needed. This will change the required heat sink to a 1.1°C /W unit if the case-to-heat-sink interface is lubricated.

The thermal requirements can become more difficult when an amplifier is driving a reactive load. For a given magnitude of load impedance, a higher degree of reactance will cause a higher level of power dissipation within the amplifier. As a general rule, the power dissipation of an amplifier driving a  $60^{\circ}$  reactive load (usually considered to be a worst-case loudspeaker load) will be roughly that of the same amplifier driving the resistive part of that load. For example, a loudspeaker may at some frequency have impedance with a magnitude of  $8\Omega$  and a phase angle of  $60^{\circ}$ . The real part of this load will then be  $4\Omega$ , and the amplifier power dissipation will roughly follow the curve of power dissipation with a  $4\Omega$  resistor.

#### TYPICAL APPLICATION CIRCUIT IN SPLIT SUPPLY





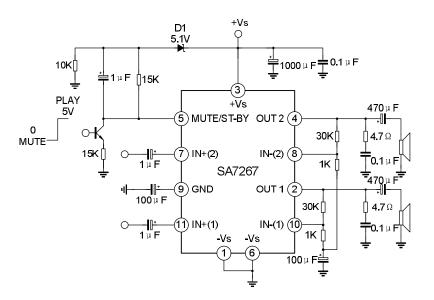
SW1	SW2			
Α	Α	Stand-by		
А	В	Stand-by		
В	В	Mute		
В	Α	Play		

Note: Figures for the SA7267.

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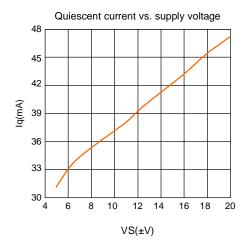
# TYPICAL APPLICATION CIRCUIT IN SINGLE SUPPLY

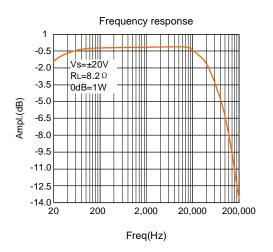


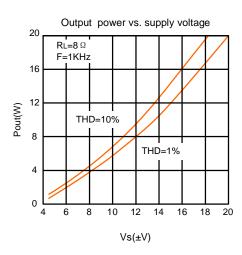
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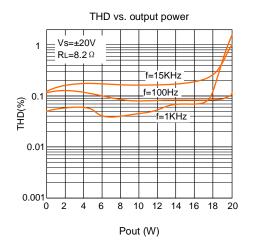


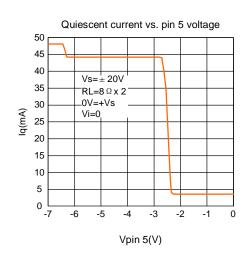
## **ELECTRICAL CHARACTERISTICS CURVES**

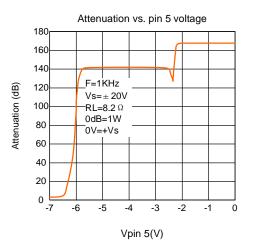








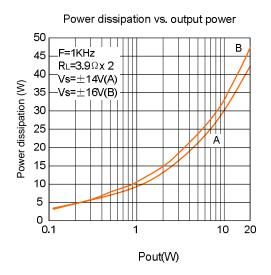


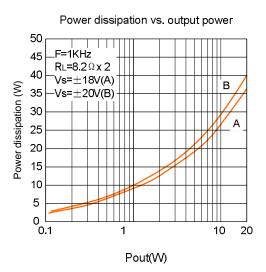


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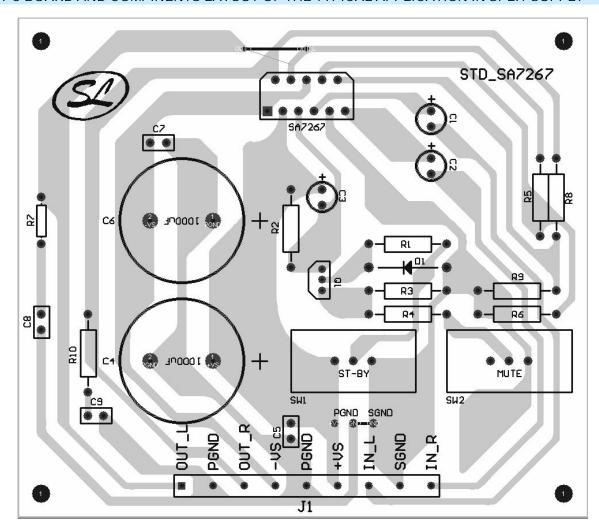


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## PC BOARD AND COMPINENTS LAYOUT OF THE TYPICAL APPLICATION IN SPLIT SUPPLY





# **APPLICATION SUGGEST**

The recommended values of the external components shown are the Typical Application Circuit in Split

Supply:

Supply:					
COMPONENTS	RECOMMENDED VALUE	PURPOSE	LARGER THAN RECOMMENDED VALUE	SMALLER THAN RECOMMENDED VALUE	
R1	10ΚΩ	Mute Circuit	Increase of Dz Biasing Current		
R2	15ΚΩ	Mute Circuit	VMUTE/STBY Shifted Downward	VMUTE/STBY Shifted Upward	
R3	18ΚΩ	Mute Circuit	VMUTE/STBY Shifted Upward	VMUTE/STBY Shifted Downward	
R4	15ΚΩ	Mute Circuit	VMUTE/STBY Shifted Upward	VMUTE/STBY Shifted Downward	
R5, R8	18ΚΩ	Closed Loop Gain	Increase of Gain		
R6, R9	560Ω	Setting*	Decrease of Gain		
R7, R10	4.7Ω	Frequency Stability	Danger of Oscillations	Danger of Oscillations	
C1, C2	1μF	Input DC Decoupling		Higher Low Frequency Cutoff	
СЗ	1μF	St-By/Mute Time Constant	Larger On/Off Time	Smaller On/Off Time	
C4, C6	1000μF	Supply Bypass		Danger of Oscillations	
C5, C7	0.1μF	Supply Bypass		Danger of Oscillations	
C8, C9	0.1μF	Frequency Stability			
Dz	5.1V	Mute Circuit			
Q1	BC107	Mute Circuit			

<sup>\*</sup> Closed loop gain has to be ≥ 25dB.

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# PACKAGE OUTLINE

